

8K Microwire Compatible Serial EEPROM

Device Selection Table

| Part Number | Vcc Range | ORG Pin | PE Pin | Word Size | Temp Ranges | Packages |
|-------------|-----------|---------|--------|--------------|-------------|-------------------|
| 93AA76A | 1.8-5.5 | No | No | 8-bit | I | OT, SN |
| 93AA76B | 1.8-5-5 | No | No | 16-bit | I | OT, SN |
| 93LC76A | 2.5-5.5 | No | No | 8-bit | I, E | OT, SN |
| 93LC76B | 2.5-5.5 | No | No | 16-bit | I, E | OT, SN |
| 93C76A | 4.5-5.5 | No | No | 8-bit | I, E | OT, SN |
| 93C76B | 4.5-5.5 | No | No | 16-bit | I, E | OT, SN |
| 93AA76C | 1.8-5.5 | Yes | Yes | 8- or 16-bit | I | P, SN, ST, MS, MC |
| 93LC76C | 2.5-5.5 | Yes | Yes | 8- or 16-bit | I, E | P, SN, ST, MS, MC |
| 93C76C | 4.5-5.5 | Yes | Yes | 8- or 16-bit | I, E | P, SN, ST, MS, MC |

Features:

- Low-Power CMOS Technology
- ORG Pin to Select Word Size for '76C' Version
- 1024 x 8-bit Organization 'A' Devices (no ORG)
- 512 x 16-bit Organization 'B' Devices (no ORG)
- Program Enable Pin to Write-Protect the Entire Array ('76C' version only)
- Self-Timed Erase/Write Cycles (including Auto-Erase)
- Automatic ERAL Before WRAL
- Power-On/Off Data Protection Circuitry
- Industry Standard 3-Wire Serial I/O
- Device Status Signal (Ready/Busy)
- Sequential Read Function
- 1,000,000 Erase/Write Cycles
- Data Retention > 200 Years
- Pb-free and RoHS Compliant
- Temperature Ranges Supported:
 - Industrial (I) -40°C to +85°C
 - Automotive (E) -40°C to +125°C

Pin Function Table

| Name | Function |
|------|-------------------------------------|
| CS | Chip Select |
| CLK | Serial Data Clock |
| DI | Serial Data Input |
| DO | Serial Data Output |
| Vss | Ground |
| PE | Program Enable – 93XX76C only |
| ORG | Memory Configuration – 93XX76C only |
| Vcc | Power Supply |

Description:

The Microchip Technology Inc. 93XX76A/B/C devices are 8Kbit, low-voltage, serial Electrically Erasable PROMs (EEPROM). Word-selectable devices such as the 93XX76C are dependent upon external logic levels driving the ORG pin to set word size. In the SOT-23 package, the 93XX76A devices provide dedicated 8-bit memory organization, while the 93XX76B devices provide dedicated 16-bit memory organization. A Program Enable (PE) pin allows the user to write-protect the entire memory array. Advanced CMOS technology makes these devices ideal for low-power, nonvolatile memory applications. The 93XX Series is available in standard packages including 8-lead PDIP and SOIC, and advanced packaging including 8-lead MSOP, 6-lead SOT-23, 8-lead 2x3 DFN and 8-lead TSSOP. All packages are Pb-free (Matte Tin) finish.

Package Types (not to scale)

| | /SOIC SN) | SOT-2 (OT) | - |
|--|--|--|---------------------|
| CS =1 CLK =2 DI =3 DO =4 *93XX76 | 8 | DOCT VSSC 2 DICT 3 | 6усс 5сс 4сск |
| | P/MSOP ; MS) 8 ┺ Vcc 7 ┺ PE 6 ┺ ORG 5 ┺ Vss | DF (MC CS CLK 2 DI 3 DO 4 | |

1.0 ELECTRICAL CHARACTERISTICS

Absolute Maximum Ratings (†)

| Vcc | 7.0V |
|--|--------------------|
| All inputs and outputs w.r.t. Vss | -0.6V to Vcc +1.0V |
| Storage temperature | 65°C to +150°C |
| Ambient temperature with power applied | 40°C to +125°C |
| ESD protection on all pins | |

† NOTICE: Stresses above those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at those or any other conditions above those indicated in the operational listings of this specification is not implied. Exposure to maximum rating conditions for extended periods may affect device reliability.

TABLE 1-1: DC CHARACTERISTICS

| | | ply over the specified nerwise noted. | Industrial (Automotive | | | | C, VCC = +1.8V to 5.5V C, VCC = +2.5V to 5.5V | | |
|---------------|--------------|--|----------------------------|---------------|------------------|----------------|--|--|--|
| Param. No. | Symbol | Parameter | Min Typ M | | Мах | Units | Conditions | | |
| D1 | ViH1 ViH2 | High-level input voltage | 2.0 0.7 Vcc | | Vcc +1 Vcc +1 | > > | Vcc ≥ 2.7V Vcc < 2.7V | | |
| D2 | Vi∟1 Vi∟2 | Low-level input voltage | -0.3 -0.3 | | 0.8 0.2 Vcc | > > | Vcc ≥ 2.7V Vcc < 2.7V | | |
| D3 | Vol1 Vol2 | Low-level output voltage | | | 0.4 0.2 | V V | | | |
| D4 | Vон1 Vон2 | High-level output voltage | 2.4 Vcc - 0.2 | | _ | V V | IOH = -400 μA, VCC = 4.5V IOH = -100 μA, VCC = 2.5V | | |
| D5 | ILI | Input leakage current | _ | _ | ±1 | μA | VIN = VSS or VCC | | |
| D6 | Ilo | Output leakage current | — | _ | ±1 | μΑ | VOUT = VSS or VCC | | |
| D7 | CIN, COUT | Pin capacitance (all inputs/ outputs) | — | _ | 7 | pF | VIN/VOUT = 0V (Note 1) TA = 25°C, FCLK = 1 MHz | | |
| D8 | ICC write | Write current | _ | — 500 | 3 | mA μA | FCLK = 3 MHz, VCC = 5.5V FCLK = 2 MHz, VCC = 2.5V | | |
| D9 | ICC read | Read current | | — — 100 | 1 500 — | mA μA μA | FCLK = 3 MHz, VCC = 5.5V FCLK = 2 MHz, VCC = 3.0V FCLK = 2 MHz, VCC = 2.5V | | |
| D10 | Iccs | Standby current | | | 1 5 | μΑ μΑ | I – Temp E – Temp CLK = CS = 0V ORG = DI = PE = Vss or Vcc (Note 2) (Note 3) | | |
| D11 | VPOR | Vcc voltage detect | _ | 1.5 3.8 | | V V | (Note 1) 93AA76A/B/C, 93LC76A/B/C 93C76A/B/C | | |

Note 1: This parameter is periodically sampled and not 100% tested.

2: ORG and PE pins not available on 'A' or 'B' versions.

3: Ready/Busy status must be cleared from DO; see Section 3.4 "Data Out (DO)".

TABLE 1-2: AC CHARACTERISTICS

| | | ply over the specified nerwise noted. | Industrial (Automotiv | | | to +85°C, Vcc = +1.8V to 5.5V to +125°C, Vcc = +2.5V to 5.5V |
|---------------|--------|--|---------------------------|-------------------|-------------------|--|
| Param. No. | Symbol | Parameter | Min | Мах | Units | Conditions |
| A1 | FCLK | Clock frequency | _ | 3 2 1 | MHz MHz MHz | 4.5V ≤ VCC < 5.5V 2.5V ≤ VCC < 4.5V 1.8V ≤ VCC < 2.5V |
| A2 | Тскн | Clock high time | 200 250 450 | _ | ns ns ns | 4.5V ≤ VCC < 5.5V 2.5V ≤ VCC < 4.5V 1.8V ≤ VCC < 2.5V |
| A3 | Тск∟ | Clock low time | 100 200 450 | _ | ns ns ns | 4.5V ≤ VCC < 5.5V 2.5V ≤ VCC < 4.5V 1.8V ≤ VCC < 2.5V |
| A4 | Tcss | Chip Select setup time | 50 100 250 | _ | ns ns ns | 4.5V ≤ VCC < 5.5V 2.5V ≤ VCC < 4.5V 1.8V ≤ VCC < 2.5V |
| A5 | Тсѕн | Chip Select hold time | 0 | | ns | 1.8V ≤ VCC < 5.5V |
| A6 | TCSL | Chip Select low time | 250 | — | ns | 1.8V ≤ VCC < 5.5V |
| A7 | TDIS | Data input setup time | 50 100 250 | _ | ns ns ns | 4.5V ≤ VCC < 5.5V 2.5V ≤ VCC < 4.5V 1.8V ≤ VCC < 2.5V |
| A8 | Тон | Data input hold time | 50 100 250 | _ | ns ns ns | 4.5V ≤ VCC < 5.5V 2.5V ≤ VCC < 4.5V 1.8V ≤ VCC < 2.5V |
| A9 | Tpd | Data output delay time | _ | 100 250 400 | ns ns ns | 4.5V ≤ VCC < 5.5V, CL = 100 pF 2.5V ≤ VCC < 4.5V, CL = 100 pF 1.8V ≤ VCC < 2.5V, CL = 100 pF |
| A10 | Tcz | Data output disable time | — | 100 200 | ns ns | 4.5V ≤ VCC < 5.5V, (Note 1) 1.8V ≤ VCC < 4.5V, (Note 1) |
| A11 | Tsv | Status valid time | — | 200 300 500 | ns ns ns | 4.5V ≤ Vcc < 5.5V, CL = 100 pF 2.5V ≤ Vcc < 4.5V, CL = 100 pF 1.8V ≤ Vcc < 2.5V, CL = 100 pF |
| A12 | Twc | Program cycle time | — | 5 | ms | Erase/Write mode (AA and LC versions) |
| A13 | Twc | | _ | 2 | ms | Erase/Write mode (93C versions) |
| A14 | TEC | | _ | 6 | ms | ERAL mode, $4.5V \le VCC \le 5.5V$ |
| A15 | TwL | | _ | 15 | ms | WRAL mode, $4.5V \le VCC \le 5.5V$ |
| A16 | _ | Endurance | 1M | | cycles | 25°C, Vcc = 5.0V, (Note 2) |

Note 1: This parameter is periodically sampled and not 100% tested.

2: This application is not tested but ensured by characterization. For endurance estimates in a specific application, please consult the Total Endurance[™] Model, which may be obtained from Microchip's web site at www.microchip.com.

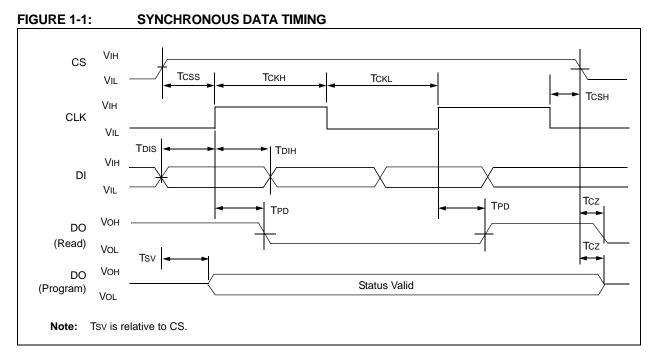


TABLE 1-3: INSTRUCTION SET FOR X16 ORGANIZATION (93XX76B OR 93XX76C WITH ORG = 1)

| Instruction | SB | Opcode | | | | | Add | ress | | | | | Data In | Data Out | Req. CLK Cycles |
|-------------|----|--------|---|----|----|----|-----|------|----|----|----|----|---------|-----------|--------------------|
| READ | 1 | 10 | Х | A8 | A7 | A6 | A5 | A4 | A3 | A2 | A1 | A0 | _ | D15-D0 | 29 |
| EWEN | 1 | 00 | 1 | 1 | x | x | х | х | x | х | x | х | - | High-Z | 13 |
| ERASE | 1 | 11 | Х | A8 | A7 | A6 | A5 | A4 | A3 | A2 | A1 | A0 | | (RDY/BSY) | 13 |
| ERAL | 1 | 00 | 1 | 0 | Х | Х | Х | Х | Х | Х | Х | Х | | (RDY/BSY) | 13 |
| WRITE | 1 | 01 | Х | A8 | A7 | A6 | A5 | A4 | A3 | A2 | A1 | A0 | D15-D0 | (RDY/BSY) | 29 |
| WRAL | 1 | 00 | 0 | 1 | х | x | х | х | x | х | x | х | D15-D0 | (RDY/BSY) | 29 |
| EWDS | 1 | 00 | 0 | 0 | x | x | x | х | x | х | x | x | _ | High-Z | 13 |

TABLE 1-4: INSTRUCTION SET FOR X8 ORGANIZATION (93XX76A OR 93XX76C WITH ORG = 0)

| Instruction | SB | Opcode | | Address | | | | | | | | Data In | Data Out | Req. CLK Cycles | | |
|-------------|----|--------|---|---------|----|----|----|----|----|----|----|---------|----------|--------------------|-----------|----|
| READ | 1 | 10 | Х | A9 | A8 | A7 | A6 | A5 | A4 | A3 | A2 | A1 | A0 | _ | D7-D0 | 22 |
| EWEN | 1 | 00 | 1 | 1 | х | х | х | х | x | х | х | x | х | _ | High-Z | 14 |
| ERASE | 1 | 11 | Х | A9 | A8 | A7 | A6 | A5 | A4 | A3 | A2 | A1 | A0 | _ | (RDY/BSY) | 14 |
| ERAL | 1 | 00 | 1 | 0 | x | x | x | x | x | x | x | x | х | _ | (RDY/BSY) | 14 |
| WRITE | 1 | 01 | Х | A9 | A8 | A7 | A6 | A5 | A4 | A3 | A2 | A1 | A0 | D7-D0 | (RDY/BSY) | 22 |
| WRAL | 1 | 00 | 0 | 1 | x | x | x | x | x | x | х | x | х | D7-D0 | (RDY/BSY) | 22 |
| EWDS | 1 | 00 | 0 | 0 | x | x | x | x | x | x | x | x | х | | High-Z | 14 |

2.0 FUNCTIONAL DESCRIPTION

When the ORG pin (93XX76C) is connected to Vcc, the (x16) organization is selected. When it is connected to ground, the (x8) organization is selected. Instructions, addresses and write data are clocked into the DI pin on the rising edge of the clock (CLK). The DO pin is normally held in a High-Z state except when reading data from the device, or when checking the Ready/ Busy status during a programming operation. The Ready/Busy status can be verified during an Erase/ Write operation by polling the DO pin; DO low indicates that programming is still in progress, while DO high indicates the device is ready. DO will enter the High-Z state on the falling edge of CS.

2.1 Start Condition

The Start bit is detected by the device if CS and DI are both high with respect to the positive edge of CLK for the first time.

Before a Start condition is detected, CS, CLK and DI may change in any combination (except to that of a Start condition), without resulting in any device operation (Read, Write, Erase, EWEN, EWDS, ERAL or WRAL). As soon as CS is high, the device is no longer in Standby mode.

An instruction following a Start condition will only be executed if the required opcode, address and data bits for any particular instruction are clocked in.

Note: When preparing to transmit an instruction, either the CLK or DI signal levels must be at a logic low as CS is toggled active high.

2.2 Data In/Data Out (DI/DO)

It is possible to connect the Data In and Data Out pins together. However, with this configuration it is possible for a "bus conflict" to occur during the "dummy zero" that precedes the read operation if A0 is a logic highlevel. Under such a condition the voltage level seen at Data Out is undefined and will depend upon the relative impedances of Data Out and the signal source driving A0. The higher the current sourcing capability of the driver, the higher the voltage at the Data Out pin. In order to limit this current, a resistor should be connected between DI and DO.

2.3 Data Protection

All modes of operation are inhibited when Vcc is below a typical voltage of 1.5V for '93AA' and '93LC' devices or 3.8V for '93C' devices.

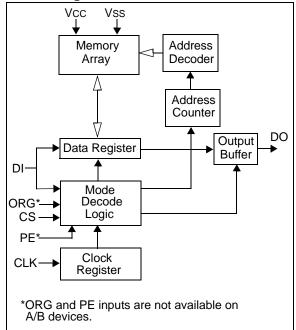
The EWEN and EWDS commands give additional protection against accidentally programming during normal operation.

Note: For added protection, an EWDS command should be performed after every write operation and an external $10 \text{ k}\Omega$ pull-down protection resistor should be added to the CS pin.

After power-up the device is automatically in the EWDS mode. Therefore, an EWEN instruction must be performed before the initial ERASE or WRITE instruction can be executed.

Note: To prevent accidental writes to the array in the 93XX76C devices, set the PE pin to a logic low.

Block Diagram

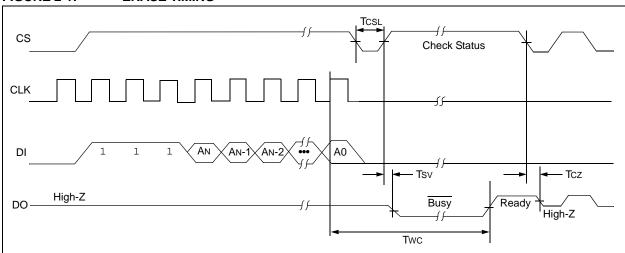


2.4 Erase

The ERASE instruction forces all data bits of the specified address to the logical '1' state. The rising edge of CLK before the last address bit initiates the write cycle.

The DO pin indicates the Ready/Busy status of the device if CS is brought high after a minimum of 250 ns low (TCSL). DO at logical '0' indicates that programming is still in progress. DO at logical '1' indicates that the register at the specified address has been erased and the device is ready for another instruction.

Note: After the Erase cycle is complete, issuing a Start bit and then taking CS low will clear the Ready/Busy status from DO.



2.5 Erase All (ERAL)

The Erase All (ERAL) instruction will erase the entire memory array to the logical '1' state. The ERAL cycle is identical to the erase cycle, except for the different opcode. The ERAL cycle is completely self-timed. The rising edge of CLK before the last data bit initiates the write cycle. Clocking of the CLK pin is not necessary after the device has entered the ERAL cycle. The DO pin indicates the Ready/Busy status of the device, if CS is brought high after a minimum of 250 ns low (TCSL).

Note: After the ERAL command is complete, issuing a Start bit and then taking CS low will clear the Ready/Busy status from DO.

VCC must be \geq 4.5V for proper operation of ERAL.

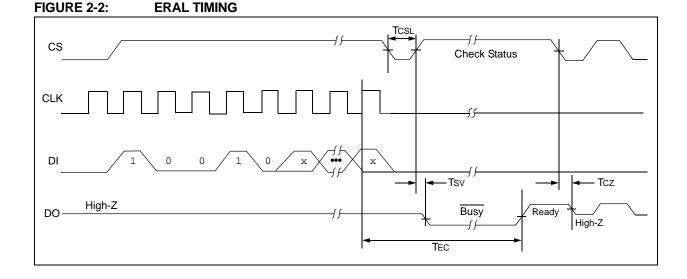


FIGURE 2-1: ERASE TIMING

2.6 Erase/Write Disable and Enable (EWDS/EWEN)

The 93XX76A/B/C powers up in the Erase/Write Disable (EWDS) state. All programming modes must be preceded by an Erase/Write Enable (EWEN) instruction.

Once the EWEN instruction is executed, programming remains enabled until an EWDS instruction is executed or Vcc is removed from the device.

To protect against accidental data disturbance, the EWDS instruction can be used to disable all erase/write functions and should follow all programming operations. Execution of a READ instruction is independent of both the EWEN and EWDS instructions.

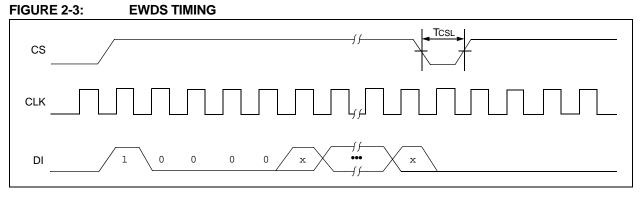
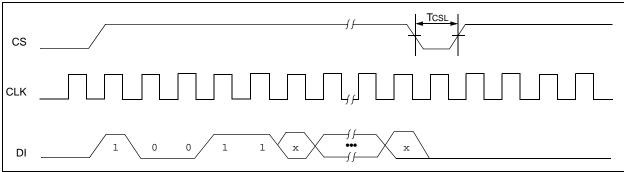


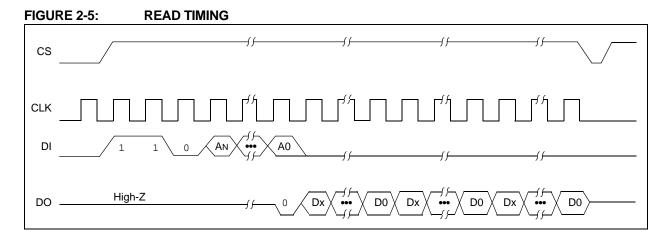
FIGURE 2-4: EWEN TIMING



2.7 Read

The READ instruction outputs the serial data of the addressed memory location on the DO pin. A dummy zero bit precedes the 8-bit (If ORG pin is low or A-version devices) or 16-bit (If ORG pin is high or B-version devices) output string.

The output data bits will toggle on the rising edge of the CLK and are stable after the specified time delay (TPD). Sequential read is possible when CS is held high. The memory data will automatically cycle to the next register and output sequentially.

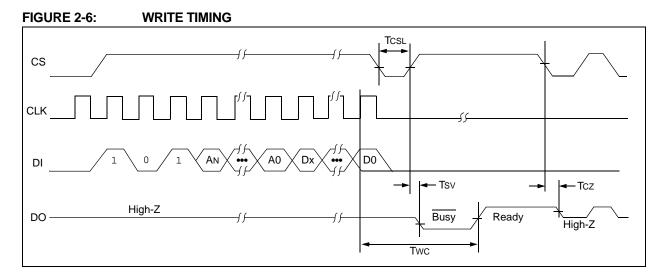


2.8 Write

The WRITE instruction is followed by 8 bits (if ORG is low or A-version devices) or 16 bits (if ORG pin is high or B-version devices) of data which are written into the specified address. The self-timed auto-erase and programming cycle is initiated by the rising edge of CLK on the last data bit. The DO pin indicates the Ready/Busy status of the device, if CS is brought high after a minimum of 250 ns low (TCSL). DO at logical '0' indicates that programming is still in progress. DO at logical '1' indicates that the register at the specified address has been written with the data specified and the device is ready for another instruction.

Note: The write sequence requires a logic high signal on the PE pin prior to the rising edge of the last data bit.

Note: After the Write cycle is complete, issuing a Start bit and then taking CS low will clear the Ready/Busy status from DO.



2.9 Write All (WRAL)

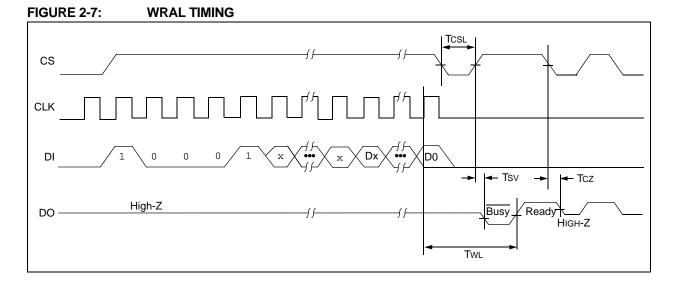
The Write All (WRAL) instruction will write the entire memory array with the data specified in the command. The self-timed auto-erase and programming cycle is initiated by the rising edge of CLK on the last data bit. Clocking of the CLK pin is not necessary after the device has entered the WRAL cycle. The WRAL command includes an automatic ERAL cycle for the device, so the WRAL instruction does not require an ERAL instruction. However, the chip must be in the EWEN status.

The DO pin indicates the Ready/Busy status of the device if CS is brought high after a minimum of 250 ns low (TCSL).

Note: The write sequence requires a logic high signal on the PE pin prior to the rising edge of the last data bit.

Note: After the Write All cycle is complete, issuing a Start bit and then taking CS low will clear the Ready/Busy status from DO.

VCC must be \geq 4.5V for proper operation of WRAL.



3.0 PIN DESCRIPTIONS

TABLE 3-1:PIN DESCRIPTIONS

| Name | SOIC/PDIP/MSOP/ TSSOP/DFN | SOT-23 | Function | |
|------|------------------------------|--------|-----------------------------|--|
| CS | 1 | 5 | Chip Select | |
| CLK | 2 | 4 | Serial Clock | |
| DI | 3 | 3 | Data In | |
| DO | 4 | 1 | Data Out | |
| Vss | 5 | 2 | Ground | |
| ORG | 6 | — | Organization/93XX76C only | |
| PE | 7 | | Program Enable/93XX76C only | |
| Vcc | 8 | 6 | Power Supply | |

3.1 Chip Select (CS)

A high level selects the device; a low level deselects the device and forces it into Standby mode. However, a programming cycle that is already in progress will be completed, regardless of the Chip Select (CS) input signal. If CS is brought low during a program cycle, the device will go into Standby mode as soon as the programming cycle is completed.

CS must be low for 250 ns minimum (TCSL) between consecutive instructions. If CS is low, the internal control logic is held in a Reset status.

3.2 Serial Clock (CLK)

The Serial Clock is used to synchronize the communication between a master device and the 93XX series device. Opcodes, address and data bits are clocked in on the positive edge of CLK. Data bits are also clocked out on the positive edge of CLK.

CLK can be stopped anywhere in the transmission sequence (at high or low-level) and can be continued anytime with respect to Clock High Time (TCKH) and Clock Low Time (TCKL). This gives the controlling master freedom in preparing opcode, address and data.

CLK is a "don't care" if CS is low (device deselected). If CS is high, but the Start condition has not been detected (DI = 0), any number of clock cycles can be received by the device without changing its status (i.e., waiting for a Start condition).

CLK cycles are not required during the self-timed write (i.e., auto erase/write) cycle.

After detection of a Start condition the specified number of clock cycles (respectively, low-to-high transitions of CLK) must be provided. These clock cycles are required to clock in all required opcode, address and data bits before an instruction is executed. CLK and DI then become "don't care" inputs waiting for a new Start condition to be detected.

3.3 Data In (DI)

Data In (DI) is used to clock in a Start bit, opcode, address and data synchronously with the CLK input.

3.4 Data Out (DO)

Data Out (DO) is used in the Read mode to output data synchronously with the CLK input (TPD after the positive edge of CLK).

This pin also provides Ready/Busy status information during erase and write cycles. Ready/Busy status information is available on the DO pin if CS is brought high after being low for minimum Chip Select Low Time (TCSL) and an erase or write operation has been initiated.

The Status signal is not available on DO, if CS is held low during the entire erase or write cycle. In this case, DO is in the High-Z mode. If status is checked after the erase/write cycle, the data line will be high to indicate the device is ready.

Note: After a programming cycle is complete, issuing a Start bit and then taking CS low will clear the Ready/Busy status from DO.

3.5 Organization (ORG)

When the ORG pin is connected to VCC or Logic HI, the (x16) memory organization is selected. When the ORG pin is tied to VSS or Logic LO, the (x8) memory organization is selected. For proper operation, ORG must be tied to a valid logic level.

93XX76A devices are always (x8) organization and 93XX76B devices are always (x16) organization.

3.6 Program Enable (PE)

This pin allows the user to enable or disable the ability to write data to the memory array. If the PE pin is tied to Vcc, the device can be programmed. If the PE pin is tied to Vss, programming will be inhibited. This pin cannot be floated – it must be tied to Vcc or Vss. PE is not available on 93XX76A or 93XX76B. On those devices, programming is always enabled.

4.0 PACKAGING INFORMATION

4.1 Package Marking Information

8-Lead MSOP (150 mil)

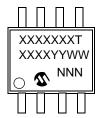


6-Lead SOT-23

| Д | П | П |
|------------|----|---|
| Х | XN | N |
| \bigcirc | | |
| П | | П |



8-Lead SOIC



8-Lead TSSOP



8-Lead 2x3 DFN





Example:

| 93LC76C |
|-----------|
| I/P @31L7 |
| 0528 |
| 0 |
| |





Example:



Example:



| | | | 1st Line Mark | king Codes | | |
|-------------|-------|--------|---------------|------------|---------|---------|
| Part Number | TECOD | MCOD | SOT | -23 | DF | N |
| | TSSOP | MSOP | l Temp. | E Temp. | I Temp. | E Temp. |
| 93AA76A | — | — | 4BNN | | | |
| 93AA76B | — | — | 4LNN | — | _ | — |
| 93AA76C | A76C | 3A76CT | — | — | 3B1 | — |
| 93LC76A | — | | 4ENN | 4FNN | _ | — |
| 93LC76B | — | — | 4PNN | 4RNN | _ | — |
| 93LC76C | L76C | 3L76CT | — | — | 3B4 | 3B5 |
| 93C76A | — | | 4HNN | 4JNN | _ | — |
| 93C76B | — | — | 4TNN | 4UNN | — | — |
| 93C76C | C76C | 3C76CT | — | — | 3B7 | 3B8 |

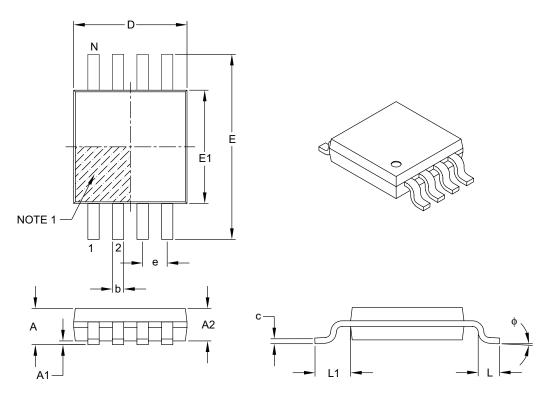
Note: T = Temperature grade (I, E)

NN = Alphanumeric traceability code

| Legend | d: XXX T YY WW NNN @3 | Part number or part number code Temperature (I, E) Year code (last digit of calendar year) Year code (last 2 digits of calendar year) Week code (week of January 1 is week '01') Alphanumeric traceability code (2 characters for small packages) Pb-free JEDEC designator for Matte Tin (Sn) |
|--------|--------------------------------------|---|
| Note: | , | small packages with no room for the Pb-free JEDEC designator marking will only appear on the outer carton or reel label. |
| Note: | be carrie | ent the full Microchip part number cannot be marked on one line, it will d over to the next line, thus limiting the number of available s for customer-specific information. |

8-Lead Plastic Micro Small Outline Package (MS) [MSOP]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



| Units | | MILLIMETERS | | |
|--------------------------|-----------|-------------|----------|------|
| Dimensio | on Limits | MIN | NOM | MAX |
| Number of Pins | Ν | | 8 | |
| Pitch | е | | 0.65 BSC | |
| Overall Height | А | _ | - | 1.10 |
| Molded Package Thickness | A2 | 0.75 | 0.85 | 0.95 |
| Standoff | A1 | 0.00 | - | 0.15 |
| Overall Width | E | | 4.90 BSC | |
| Molded Package Width | E1 | | 3.00 BSC | |
| Overall Length | D | | 3.00 BSC | |
| Foot Length | L | 0.40 | 0.60 | 0.80 |
| Footprint | L1 | 0.95 REF | | |
| Foot Angle | φ | 0° | - | 8° |
| Lead Thickness | С | 0.08 | - | 0.23 |
| Lead Width | b | 0.22 | - | 0.40 |

Notes:

1. Pin 1 visual index feature may vary, but must be located within the hatched area.

2. Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed 0.15 mm per side.

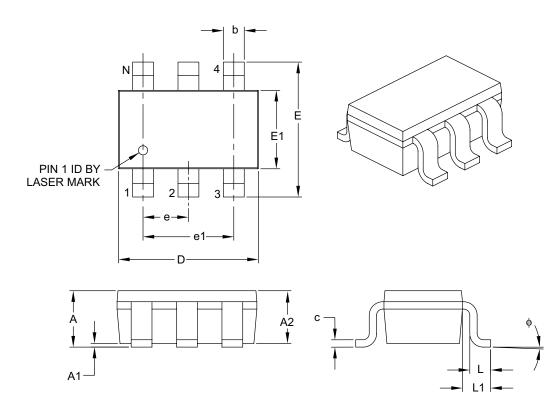
- 3. Dimensioning and tolerancing per ASME Y14.5M.
 - BSC: Basic Dimension. Theoretically exact value shown without tolerances.

REF: Reference Dimension, usually without tolerance, for information purposes only.

Microchip Technology Drawing C04-111B

6-Lead Plastic Small Outline Transistor (OT) [SOT-23]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



| | Units | | MILLIMETERS | | |
|--------------------------|----------------|------|-------------|------|--|
| Di | mension Limits | MIN | NOM | MAX | |
| Number of Pins | N | | 6 | | |
| Pitch | е | | 0.95 BSC | | |
| Outside Lead Pitch | e1 | | 1.90 BSC | | |
| Overall Height | А | 0.90 | - | 1.45 | |
| Molded Package Thickness | A2 | 0.89 | - | 1.30 | |
| Standoff | A1 | 0.00 | - | 0.15 | |
| Overall Width | E | 2.20 | - | 3.20 | |
| Molded Package Width | E1 | 1.30 | - | 1.80 | |
| Overall Length | D | 2.70 | - | 3.10 | |
| Foot Length | L | 0.10 | - | 0.60 | |
| Footprint | L1 | 0.35 | - | 0.80 | |
| Foot Angle | φ | 0° | - | 30° | |
| Lead Thickness | С | 0.08 | - | 0.26 | |
| Lead Width | b | 0.20 | _ | 0.51 | |

Notes:

1. Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed 0.127 mm per side.

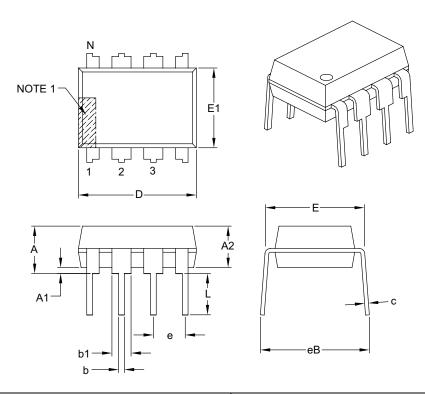
2. Dimensioning and tolerancing per ASME Y14.5M.

BSC: Basic Dimension. Theoretically exact value shown without tolerances.

Microchip Technology Drawing C04-028B

8-Lead Plastic Dual In-Line (P) – 300 mil Body [PDIP]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



| | Units | | INCHES | | |
|----------------------------|-----------|------|----------|------|--|
| Dimensio | on Limits | MIN | NOM | MAX | |
| Number of Pins | Ν | | 8 | | |
| Pitch | е | | .100 BSC | | |
| Top to Seating Plane | Α | - | - | .210 | |
| Molded Package Thickness | A2 | .115 | .130 | .195 | |
| Base to Seating Plane | A1 | .015 | - | - | |
| Shoulder to Shoulder Width | E | .290 | .310 | .325 | |
| Molded Package Width | E1 | .240 | .250 | .280 | |
| Overall Length | D | .348 | .365 | .400 | |
| Tip to Seating Plane | L | .115 | .130 | .150 | |
| Lead Thickness | С | .008 | .010 | .015 | |
| Upper Lead Width | b1 | .040 | .060 | .070 | |
| Lower Lead Width | b | .014 | .018 | .022 | |
| Overall Row Spacing § | eB | - | - | .430 | |

Notes:

1. Pin 1 visual index feature may vary, but must be located with the hatched area.

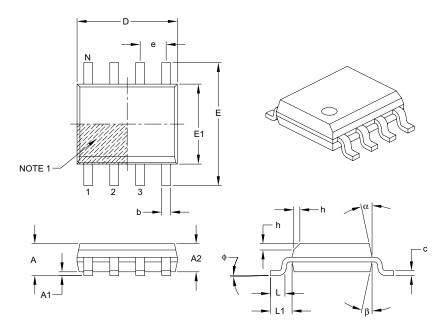
- 2. § Significant Characteristic.
- 3. Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed .010" per side.
- 4. Dimensioning and tolerancing per ASME Y14.5M.

BSC: Basic Dimension. Theoretically exact value shown without tolerances.

Microchip Technology Drawing C04-018B

8-Lead Plastic Small Outline (SN) - Narrow, 3.90 mm Body [SOIC]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



| | Units | | MILLIMETERS | | | |
|--------------------------|-------------------------|----------|-------------|------|--|--|
| | Dimension Limits | MIN | NOM | MAX | | |
| Number of Pins | N | | 8 | | | |
| Pitch | e | | 1.27 BSC | | | |
| Overall Height | A | - | - | 1.75 | | |
| Molded Package Thickness | A2 | 1.25 | - | - | | |
| Standoff § | A1 | 0.10 | - | 0.25 | | |
| Overall Width | E | 6.00 BSC | | | | |
| Molded Package Width | E1 | 3.90 BSC | | | | |
| Overall Length | D | 4.90 BSC | | | | |
| Chamfer (optional) | h | 0.25 | - | 0.50 | | |
| Foot Length | L | 0.40 | - | 1.27 | | |
| Footprint | L1 | | 1.04 REF | | | |
| Foot Angle | ф | 0° | - | 8° | | |
| Lead Thickness | С | 0.17 | - | 0.25 | | |
| Lead Width | b | 0.31 | - | 0.51 | | |
| Mold Draft Angle Top | α | 5° | - | 15° | | |
| Mold Draft Angle Bottom | β | 5° | - | 15° | | |

Notes:

1. Pin 1 visual index feature may vary, but must be located within the hatched area.

2. § Significant Characteristic.

3. Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed 0.15 mm per side.

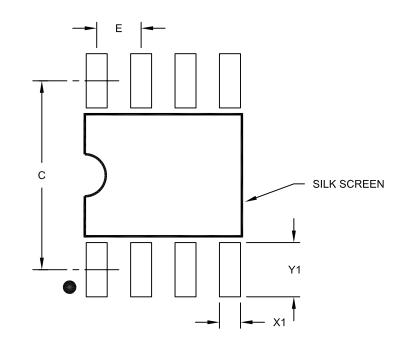
- 4. Dimensioning and tolerancing per ASME Y14.5M.
 - BSC: Basic Dimension. Theoretically exact value shown without tolerances.

REF: Reference Dimension, usually without tolerance, for information purposes only.

Microchip Technology Drawing C04-057B

8-Lead Plastic Small Outline (SN) – Narrow, 3.90 mm Body [SOIC]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



RECOMMENDED LAND PATTERN

| Units | | MILLIMETERS | | |
|-------------------------|------------------|-------------|----------|------|
| Dimension | Dimension Limits | | NOM | MAX |
| Contact Pitch | E | | 1.27 BSC | |
| Contact Pad Spacing | С | | 5.40 | |
| Contact Pad Width (X8) | X1 | | | 0.60 |
| Contact Pad Length (X8) | Y1 | | | 1.55 |

Notes:

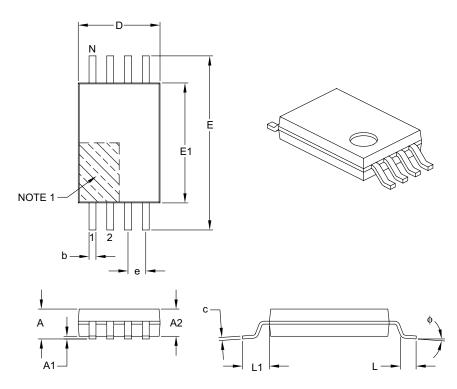
1. Dimensioning and tolerancing per ASME Y14.5M

BSC: Basic Dimension. Theoretically exact value shown without tolerances.

Microchip Technology Drawing No. C04-2057A

8-Lead Plastic Thin Shrink Small Outline (ST) – 4.4 mm Body [TSSOP]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



| | Units | | MILLIMETERS | | |
|--------------------------|----------|------|-------------|------|--|
| Dimensio | n Limits | MIN | NOM | MAX | |
| Number of Pins | Ν | | 8 | | |
| Pitch | е | | 0.65 BSC | | |
| Overall Height | А | — | - | 1.20 | |
| Molded Package Thickness | A2 | 0.80 | 1.00 | 1.05 | |
| Standoff | A1 | 0.05 | _ | 0.15 | |
| Overall Width | E | | 6.40 BSC | | |
| Molded Package Width | E1 | 4.30 | 4.40 | 4.50 | |
| Molded Package Length | D | 2.90 | 3.00 | 3.10 | |
| Foot Length | L | 0.45 | 0.60 | 0.75 | |
| Footprint | L1 | | 1.00 REF | | |
| Foot Angle | φ | 0° | _ | 8° | |
| Lead Thickness | с | 0.09 | _ | 0.20 | |
| Lead Width | b | 0.19 | _ | 0.30 | |

Notes:

1. Pin 1 visual index feature may vary, but must be located within the hatched area.

2. Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed 0.15 mm per side.

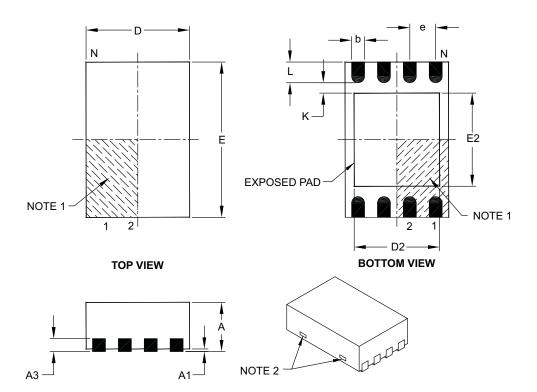
- 3. Dimensioning and tolerancing per ASME Y14.5M.
 - BSC: Basic Dimension. Theoretically exact value shown without tolerances.

REF: Reference Dimension, usually without tolerance, for information purposes only.

Microchip Technology Drawing C04-086B

8-Lead Plastic Dual Flat, No Lead Package (MC) – 2x3x0.9 mm Body [DFN]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



| | Units | | 3 | |
|------------------------|------------------|------|----------|------|
| | Dimension Limits | MIN | NOM | MAX |
| Number of Pins | N | | 8 | |
| Pitch | e | | 0.50 BSC | |
| Overall Height | А | 0.80 | 0.90 | 1.00 |
| Standoff | A1 | 0.00 | 0.02 | 0.05 |
| Contact Thickness | A3 | | 0.20 REF | |
| Overall Length | D | | 2.00 BSC | |
| Overall Width | E | | 3.00 BSC | |
| Exposed Pad Length | D2 | 1.30 | _ | 1.55 |
| Exposed Pad Width | E2 | 1.50 | _ | 1.75 |
| Contact Width | b | 0.20 | 0.25 | 0.30 |
| Contact Length | L | 0.30 | 0.40 | 0.50 |
| Contact-to-Exposed Pad | К | 0.20 | _ | - |

Notes:

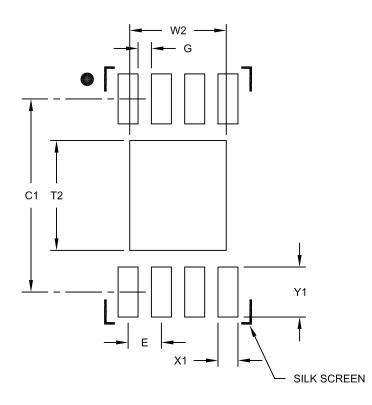
- 1. Pin 1 visual index feature may vary, but must be located within the hatched area.
- 2. Package may have one or more exposed tie bars at ends.
- 3. Package is saw singulated.
- 4. Dimensioning and tolerancing per ASME Y14.5M.
 - BSC: Basic Dimension. Theoretically exact value shown without tolerances.

REF: Reference Dimension, usually without tolerance, for information purposes only.

Microchip Technology Drawing C04-123C

8-Lead Plastic Dual Flat, No Lead Package (MC) – 2x3x0.9 mm Body [DFN]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



RECOMMENDED LAND PATTERN

| Units | | 1 | MILLIMETER | S |
|----------------------------|------------------|------|------------|------|
| Dimensio | Dimension Limits | | NOM | MAX |
| Contact Pitch | E | | 0.50 BSC | |
| Optional Center Pad Width | W2 | | | 1.45 |
| Optional Center Pad Length | T2 | | | 1.75 |
| Contact Pad Spacing | C1 | | 2.90 | |
| Contact Pad Width (X8) | X1 | | | 0.30 |
| Contact Pad Length (X8) | Y1 | | | 0.75 |
| Distance Between Pads | G | 0.20 | | |

Notes:

1. Dimensioning and tolerancing per ASME Y14.5M

BSC: Basic Dimension. Theoretically exact value shown without tolerances.

Microchip Technology Drawing No. C04-2123A

APPENDIX A: REVISION HISTORY

Revision C

Corrections to Section 1.0, Electrical Characteristics. Section 4.1, 6-Lead SOT-23 package to OT.

Revision D

Corrections to Device Selection Table, Table 1-1, Table 1-2, Section 2.4, Section 2.5, Section 2.8 and Section 2.9. Added note to Figure 2-7.

Revision E

Added DFN package.

Revision F

Added notes throughout.

Revision G

Revised note in Sections 2.8 and 2.9. Replaced DFN package drawing.

Revision H

Updated Package Drawings.

Revision J (10/2007)

Revised Device Selection Table; Revised Pin Function Table; Revised Package Types; Revised Table 3-1; Replaced Package Drawings; Revised Product ID System.

Revision K (5/2008)

Revised Figures 2-1, 2-2, 2-6 and 2-7; Revised Package Marking Information; Replaced Package Drawings.

THE MICROCHIP WEB SITE

Microchip provides online support via our WWW site at www.microchip.com. This web site is used as a means to make files and information easily available to customers. Accessible by using your favorite Internet browser, the web site contains the following information:

- **Product Support** Data sheets and errata, application notes and sample programs, design resources, user's guides and hardware support documents, latest software releases and archived software
- General Technical Support Frequently Asked Questions (FAQ), technical support requests, online discussion groups, Microchip consultant program member listing
- Business of Microchip Product selector and ordering guides, latest Microchip press releases, listing of seminars and events, listings of Microchip sales offices, distributors and factory representatives

CUSTOMER CHANGE NOTIFICATION SERVICE

Microchip's customer notification service helps keep customers current on Microchip products. Subscribers will receive e-mail notification whenever there are changes, updates, revisions or errata related to a specified product family or development tool of interest.

To register, access the Microchip web site at www.microchip.com, click on Customer Change Notification and follow the registration instructions.

CUSTOMER SUPPORT

Users of Microchip products can receive assistance through several channels:

- Distributor or Representative
- Local Sales Office
- Field Application Engineer (FAE)
- Technical Support
- Development Systems Information Line

Customers should contact their distributor, representative or field application engineer (FAE) for support. Local sales offices are also available to help customers. A listing of sales offices and locations is included in the back of this document.

Technical support is available through the web site at: http://support.microchip.com

READER RESPONSE

It is our intention to provide you with the best documentation possible to ensure successful use of your Microchip product. If you wish to provide your comments on organization, clarity, subject matter, and ways in which our documentation can better serve you, please FAX your comments to the Technical Publications Manager at (480) 792-4150.

Please list the following information, and use this outline to provide us with your comments about this document.

| To: | Technical Publications Manager | Total Pages Sent |
|--------|---|---|
| RE: | Reader Response | |
| From: | Name | |
| | Company | |
| | | |
| | | |
| | Telephone: () | FAX: () |
| Applic | ation (optional): | |
| Would | l you like a reply?YN | |
| Devic | e: 93AA76A/B/C, 93LC76A/B/C, 93C76 | 6A/B/C Literature Number: DS21796K |
| Quest | ions: | |
| 1. V | hat are the best features of this docume | ent? |
| _ | | |
| _ | | |
| 2. H | ow does this document meet your hard | ware and software development needs? |
| _ | | |
| | | |
| 3. D | o you find the organization of this docur | nent easy to follow? If not, why? |
| _ | | |
| 4 W | /hat additions to the document do you th | nink would enhance the structure and subject? |
| | | |
| | | |
| 5. W | hat deletions from the document could | be made without affecting the overall usefulness? |
| | | |
| _ | | |
| 6. Is | there any incorrect or misleading inform | nation (what and where)? |
| _ | | |
| _ | | |
| 7. H | ow would you improve this document? | |
| _ | | |
| _ | | |

PRODUCT IDENTIFICATION SYSTEM

To order or obtain information, e.g., on pricing or delivery, refer to the factory or the listed sales office..

| Device Tap | be & Reel | Temperature Package Range | Lead Finish | a) b) | 93AA76C-I/MS: 8K, 1024x8 or 512x16 Serial EEPROM, MSOP package, 1.8V 93AA76AT-I/OT: 8K, 1024x8 Serial EEPROM, SOT-23 package, tape and reel, 1.8V |
|--------------------|---|---|---------------------------------------|----------|--|
| Device: | 93AA76B | 8K 1.8V Microwire Serial EE 8K 1.8V Microwire Serial EE 8K 1.8V Microwire Serial EE | PROM (x16) | c) | 93AA76CT-I/MS: 8K, 1024x8 or 512x16 Serial EEPROM, MSOP package, tape and reel, 1.8V |
| | 93LC76B 93LC76C 93C76A: | | PROM (x16) PROM w/ORG PROM (x8) | a) b) | 93LC76C-I/MS: 8K, 1024x8 or 512x16 Serial EEPROM, MSOP package, 2.5V 93LC76BT-I/OT: 8K, 512x16 Serial EEPROM, SOT-23 package, tape and reel, 2.5V |
| | 93C76B: 93C76C: | 8K 5.0V Microwire Serial EE | PROM w/ORG | a) b) | 93C76C-I/MS: 8K, 1024x8 or 512x16 Serial EEPROM, MSOP package, 5.0V 93C76AT-I/OT: 8K, 1024x8 Serial EEPROM, |
| Tape & Reel: | Blank = T = | | | | SOT-23 package, tape and reel, 5.0V |
| Temperature Range: | I = E = | -40°C to +85°C -40°C to +125°C | | | |
| Package: | MS = OT = P = SN = ST = MC = | SOT-23, 6-lead (Tape & R Plastic DIP (300 mil body) Plastic SOIC (3.90 mm bo TSSOP, 8-lead | eel only) , 8-lead | | |

NOTES:

Note the following details of the code protection feature on Microchip devices:

- Microchip products meet the specification contained in their particular Microchip Data Sheet.
- Microchip believes that its family of products is one of the most secure families of its kind on the market today, when used in the intended manner and under normal conditions.
- There are dishonest and possibly illegal methods used to breach the code protection feature. All of these methods, to our knowledge, require using the Microchip products in a manner outside the operating specifications contained in Microchip's Data Sheets. Most likely, the person doing so is engaged in theft of intellectual property.
- Microchip is willing to work with the customer who is concerned about the integrity of their code.
- Neither Microchip nor any other semiconductor manufacturer can guarantee the security of their code. Code protection does not mean that we are guaranteeing the product as "unbreakable."

Code protection is constantly evolving. We at Microchip are committed to continuously improving the code protection features of our products. Attempts to break Microchip's code protection feature may be a violation of the Digital Millennium Copyright Act. If such acts allow unauthorized access to your software or other copyrighted work, you may have a right to sue for relief under that Act.

Information contained in this publication regarding device applications and the like is provided only for your convenience and may be superseded by updates. It is your responsibility to ensure that your application meets with your specifications. MICROCHIP MAKES NO REPRESENTATIONS OR WARRANTIES OF ANY KIND WHETHER EXPRESS OR IMPLIED, WRITTEN OR ORAL, STATUTORY OR OTHERWISE, RELATED TO THE INFORMATION, INCLUDING BUT NOT LIMITED TO ITS CONDITION, QUALITY, PERFORMANCE, MERCHANTABILITY OR FITNESS FOR PURPOSE. Microchip disclaims all liability arising from this information and its use. Use of Microchip devices in life support and/or safety applications is entirely at the buyer's risk, and the buyer agrees to defend, indemnify and hold harmless Microchip from any and all damages, claims, suits, or expenses resulting from such use. No licenses are conveyed, implicitly or otherwise, under any Microchip intellectual property rights.

Trademarks

The Microchip name and logo, the Microchip logo, Accuron, dsPIC, KEELOQ, KEELOQ logo, MPLAB, PIC, PICmicro, PICSTART, PRO MATE, rfPIC and SmartShunt are registered trademarks of Microchip Technology Incorporated in the U.S.A. and other countries.

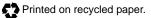
FilterLab, Linear Active Thermistor, MXDEV, MXLAB, SEEVAL, SmartSensor and The Embedded Control Solutions Company are registered trademarks of Microchip Technology Incorporated in the U.S.A.

Analog-for-the-Digital Age, Application Maestro, CodeGuard, dsPICDEM, dsPICDEM.net, dsPICworks, dsSPEAK, ECAN, ECONOMONITOR, FanSense, In-Circuit Serial Programming, ICSP, ICEPIC, Mindi, MiWi, MPASM, MPLAB Certified logo, MPLIB, MPLINK, mTouch, PICkit, PICDEM, PICDEM.net, PICtail, PIC³² logo, PowerCal, PowerInfo, PowerMate, PowerTool, REAL ICE, rfLAB, Select Mode, Total Endurance, UNI/O, WiperLock and ZENA are trademarks of Microchip Technology Incorporated in the U.S.A. and other countries.

SQTP is a service mark of Microchip Technology Incorporated in the U.S.A.

All other trademarks mentioned herein are property of their respective companies.

© 2008, Microchip Technology Incorporated, Printed in the U.S.A., All Rights Reserved.



QUALITY MANAGEMENT SYSTEM CERTIFIED BY DNV ISO/TS 16949:2002

Microchip received ISO/TS-16949:2002 certification for its worldwide headquarters, design and wafer fabrication facilities in Chandler and Tempe, Arizona; Gresham, Oregon and design centers in California and India. The Company's quality system processes and procedures are for its PIC® MCUs and dsPIC® DSCs, KEELOQ® code hopping devices, Serial EEPROMs, microperipherals, nonvolatile memory and analog products. In addition, Microchip's quality system for the design and manufacture of development systems is ISO 9001:2000 certified.



WORLDWIDE SALES AND SERVICE

AMERICAS

Corporate Office 2355 West Chandler Blvd. Chandler, AZ 85224-6199 Tel: 480-792-7200 Fax: 480-792-7277 Technical Support: http://support.microchip.com Web Address: www.microchip.com

Atlanta Duluth, GA Tel: 678-957-9614 Fax: 678-957-1455

Boston Westborough, MA Tel: 774-760-0087 Fax: 774-760-0088

Chicago Itasca, IL Tel: 630-285-0071 Fax: 630-285-0075

Dallas Addison, TX Tel: 972-818-7423 Fax: 972-818-2924

Detroit Farmington Hills, MI Tel: 248-538-2250 Fax: 248-538-2260

Kokomo Kokomo, IN Tel: 765-864-8360 Fax: 765-864-8387

Los Angeles Mission Viejo, CA Tel: 949-462-9523 Fax: 949-462-9608

Santa Clara Santa Clara, CA Tel: 408-961-6444 Fax: 408-961-6445

Toronto Mississauga, Ontario, Canada Tel: 905-673-0699 Fax: 905-673-6509

ASIA/PACIFIC

Asia Pacific Office Suites 3707-14, 37th Floor Tower 6, The Gateway Harbour City, Kowloon Hong Kong Tel: 852-2401-1200 Fax: 852-2401-3431 Australia - Sydney

Tel: 61-2-9868-6733 Fax: 61-2-9868-6755

China - Beijing Tel: 86-10-8528-2100 Fax: 86-10-8528-2104

China - Chengdu Tel: 86-28-8665-5511 Fax: 86-28-8665-7889

China - Hong Kong SAR Tel: 852-2401-1200 Fax: 852-2401-3431

China - Nanjing Tel: 86-25-8473-2460

Fax: 86-25-8473-2470 China - Qingdao Tel: 86-532-8502-7355

Fax: 86-532-8502-7205 China - Shanghai Tel: 86-21-5407-5533 Fax: 86-21-5407-5066

China - Shenyang Tel: 86-24-2334-2829 Fax: 86-24-2334-2393

China - Shenzhen Tel: 86-755-8203-2660 Fax: 86-755-8203-1760

China - Wuhan Tel: 86-27-5980-5300 Fax: 86-27-5980-5118

China - Xiamen Tel: 86-592-2388138 Fax: 86-592-2388130

China - Xian Tel: 86-29-8833-7252 Fax: 86-29-8833-7256

China - Zhuhai Tel: 86-756-3210040 Fax: 86-756-3210049

ASIA/PACIFIC

India - Bangalore Tel: 91-80-4182-8400 Fax: 91-80-4182-8422

India - New Delhi Tel: 91-11-4160-8631 Fax: 91-11-4160-8632

India - Pune Tel: 91-20-2566-1512 Fax: 91-20-2566-1513

Japan - Yokohama Tel: 81-45-471- 6166 Fax: 81-45-471-6122

Korea - Daegu Tel: 82-53-744-4301 Fax: 82-53-744-4302

Korea - Seoul Tel: 82-2-554-7200 Fax: 82-2-558-5932 or 82-2-558-5934

Malaysia - Kuala Lumpur Tel: 60-3-6201-9857 Fax: 60-3-6201-9859

Malaysia - Penang Tel: 60-4-227-8870 Fax: 60-4-227-4068

Philippines - Manila Tel: 63-2-634-9065 Fax: 63-2-634-9069

Singapore Tel: 65-6334-8870 Fax: 65-6334-8850

Taiwan - Hsin Chu Tel: 886-3-572-9526 Fax: 886-3-572-6459

Taiwan - Kaohsiung Tel: 886-7-536-4818 Fax: 886-7-536-4803

Taiwan - Taipei Tel: 886-2-2500-6610 Fax: 886-2-2508-0102

Thailand - Bangkok Tel: 66-2-694-1351 Fax: 66-2-694-1350

EUROPE

Austria - Wels Tel: 43-7242-2244-39 Fax: 43-7242-2244-393 Denmark - Copenhagen Tel: 45-4450-2828 Fax: 45-4485-2829

France - Paris Tel: 33-1-69-53-63-20 Fax: 33-1-69-30-90-79

Germany - Munich Tel: 49-89-627-144-0 Fax: 49-89-627-144-44

Italy - Milan Tel: 39-0331-742611 Fax: 39-0331-466781

Netherlands - Drunen Tel: 31-416-690399 Fax: 31-416-690340

Spain - Madrid Tel: 34-91-708-08-90 Fax: 34-91-708-08-91

UK - Wokingham Tel: 44-118-921-5869 Fax: 44-118-921-5820

X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for EEPROM category:

Click to view products by Microchip manufacturer:

Other Similar products are found below :

M29F040-70K6 718278CB 718620G AT28C256-15PU-ND 444358RB 444362FB BR93C46-WMN7TP 442652G 701986CB TC58NVG0S3HBAI4 5962-8751413XA TC58BVG0S3HBAI4 TH58NYG3S0HBAI6 CAT25320YIGT-KK CAT25320DWF LE24C162-R-E 5962-8751417YA 5962-8751409YA CAT25M01LI-G DS28E11P+ BR9016AF-WE2 LE2464DXATBG CAS93C66VP2I-GT3 DS28E25+T DS28EL15Q+T M95320-DFDW6TP DS28E05GB+T AT25320B-SSPDGV-T HE24C64WLCSPD BL24SA128B-CSRC 24FC16T-I/OT 24FC08T-I/OT M24128-BFMN6TP S-24CS04AFM-TFH-U M24C04-FMC5TG M24C16-DRMN3TPK M24C64-DFMN6TP 34AA02-EMS M95080-RMC6TG M95128-DFCS6TP/K M95128-DFDW6TP M95256-DFMN6TP M95320-RDW6TP M95640-RDW6TP AT17LV010-10CU AT24C01C-SSHM-B AT24C01D-MAHM-T AT24C04D-MAHM-T AT24C04D-SSHM-T AT24C08C-SSHM-B